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### FAIRCHILD

SEMICONDUCTOR

# 74LCX11 Low Voltage Triple 3-Input AND Gate with 5V Tolerant Inputs

#### **General Description**

The LCX11 is a triple 3-input AND gate with buffered outputs. LCX devices are designed for low voltage (2.5V or 3.3V) operation with the added capability of interfacing to a 5V signal environment.

The 74LCX11 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

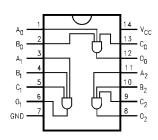
### Features

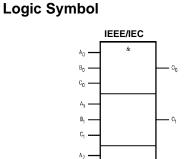
- 5V tolerant inputs and outputs
- 2.3V–3.6V V<sub>CC</sub> specifications provided
- $\blacksquare$  6.0ns t\_{PD} max (V\_{CC} = 3.3V), 10  $\mu A \ I_{CC}$  max
- Power down high impedance inputs and outputs
- $\blacksquare$  ±24 mA output drive (V\_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V Machine model > 200V

#### **Ordering Code:**

Order Number	Package Number	Package Description
74LCX11M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74LCX11SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX11MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

#### **Connection Diagram**

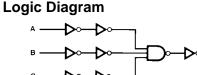




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#### **Pin Descriptions**

Pin Names	Description
A <sub>n</sub> , B <sub>n</sub> , C <sub>n</sub>	Inputs
O <sub>n</sub>	Outputs



 $B_2$ 

C2

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#### Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units			
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0		V			
VI	DC Input Voltage	-0.5 to +7.0		V			
Vo	DC Output Voltage	–0.5 to V <sub>CC</sub> + 0.5	Output in HIGH or LOW State (Note 2)	V			
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA			
Ι <sub>ΟΚ</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA			
		+50	$V_{O} > V_{CC}$	IIIA			
lo	DC Output Source/Sink Current	±50		mA			
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100		mA			
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100		mA			
T <sub>STG</sub>	Storage Temperature	-65 to +150		°C			

# Recommended Operating Conditions (Note 3)

Symbol	Parameter			Max	Units	
V <sub>CC</sub>	Supply Voltage	2.0	3.6	V		
		Data Retention	1.5	3.6	v	
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage	HIGH or LOW State	0	V <sub>CC</sub>	V	
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$V_{CC} = 3.0V - 3.6V$		±24		
		$V_{CC}=2.7V-3.0V$		±12	mA	
		$V_{CC} = 2.3V - 2.7V$		±8		
Τ <sub>Α</sub>	Free-Air Operating Temperature		-40	85	°C	
$\Delta t / \Delta V$	Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V		0	10	ns/V	

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recom-mended Operating Conditions" table will define the conditions for actual device operation.

Note 2:  $\mathsf{I}_\mathsf{O}$  Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

### **DC Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>cc</sub>	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units
Gymbol		Conditions	(V)	Min	Max	onita
VIH	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V <sub>IL</sub>	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	2.3 - 3.6	V <sub>CC</sub> - 0.2		
		$I_{OH} = -8 \text{ mA}$	2.3	1.8		
		$I_{OH} = -12mA$	2.7	2.2		V
		$I_{OH} = -18 \text{mA}$	3.0	2.4		
		$I_{OH} = -24mA$	3.0	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.3 - 3.6		0.2	
		I <sub>OL</sub> = 8 mA	2.3		0.6	
		$I_{OL} = 12mA$	2.7		0.4	V
		I <sub>OL</sub> = 16 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
l <sub>l</sub>	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μA
I <sub>OFF</sub>	Power-Off Leakage Current	$V_{I} \text{ or } V_{O} = 5.5 V$	0		10	μA
I <sub>CC</sub>	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		10	μA
		$3.6V \leq V_l \leq 5.5V$	2.3 - 3.6		±10	μΑ
∆l <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6	1	500	μΑ

### **AC Electrical Characteristics**

Symbol	Parameter	${f T}_{f A}=-40^\circ{f C}$ to $+85^\circ{f C},{f R}_{f L}=500~\Omega$						
		V <sub>CC</sub> = 3.	$3V \pm 0.3V$	V <sub>CC</sub> =	= 2.7V	V <sub>CC</sub> = 2.	$5V \pm 0.2V$	Units
		C <sub>L</sub> = 50 pF		C <sub>L</sub> = 50 pF		$C_L = 30 pF$		. Units
		Min	Max	Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	
t <sub>PHL</sub>		1.5	6.0	1.5	7.0	1.5	7.2	ns
t <sub>OSLH</sub>	Output to Output Skew		1.0					
t <sub>OSHL</sub>	(Note 4)		1.0					ns

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

# **Dynamic Switching Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C Typical	Units
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	C <sub>L</sub> = 50 pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V	3.3	0.8	
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	2.5	0.6	V
V <sub>OLV</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

# Capacitance

Symbol	Parameter	Conditions	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC}$ = 3.3V, $V_{I}$ = 0V or $V_{CC},f$ = 10 MHz	25	pF

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